

## 35kV 100mA HIGH VOLTAGE DIODE

JB289 is high reliability resin molded type high voltage diode in small size package which is sealed a multilayered mesa type silicon chip by epoxy resin.

### Features

- High speed switching
- High Current
- High surge resistivity for CRT discharge
- High reliability design
- High Voltage

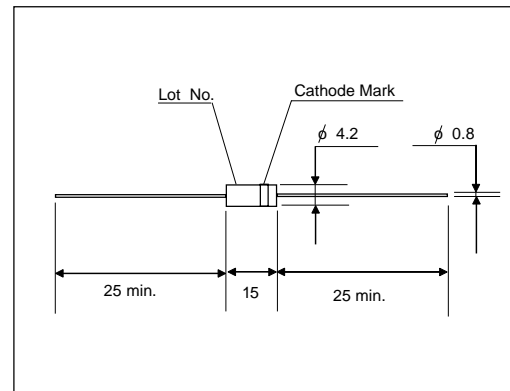
### Applications

- X light Power supply
- Laser
- Voltage doubler circuit
- Microwave emission power

### Maximum Ratings and Characteristics

- Absolute Maximum Ratings

### Outline Drawings : mm



### Cathode Mark

Type	Mark
JB289	

Items	Symbols	Condition	JB289	Units
Repetitive Peak Reverse Voltage	$V_{RRM}$		35	kV
Average Output Current	$I_o$	Ta=25°C, Resistive Load	100	mA
Surge Current	$I_{FSM}$		10	A <sub>peak</sub>
Junction Temperature	T <sub>J</sub>		155	°C
Allowable Operation Case Temperature	T <sub>c</sub>		125	°C
Storage Temperature	T <sub>stg</sub>		-40 to +155	°C

### Electrical Characteristics (Ta=25°C Unless otherwise specified)

Items	Symbols	Conditions	JB289	Units
Maximum Forward Voltage Drop	$V_F$	at 25°C, I <sub>F</sub> = 100mA	55	V
Maximum Reverse Current	IR1	at 25°C, V <sub>R</sub> = V <sub>RRM</sub>	2.0	uA
	IR2	at 100°C, V <sub>R</sub> = V <sub>RRM</sub>	50	uA
Maximum Reverse Recovery Time	T <sub>rr</sub>	at 25°C	100	nS
Junction Capacitance	C <sub>j</sub>	at 25°C, V <sub>R</sub> =0V, f=1MHz	15	pF